

T Y P E W I C F

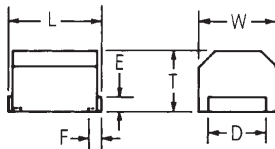
FEATURES

- Excellent solderability by reflow soldering, flow soldering or soldering iron.
- Excellent for automatic insertion in the higher density circuit design.
- Resistant to external shocks and pressure.
- Highly reliable in wide temperature and humidity ranges. Excellent Q characteristics.
- Inductance of 1 to 100 μH (WICF1008), 1 to 1000 μH (WICF1210) and 1 to 330 μH (WICF1812).
- Ideal application for power supply line, radio, auto, telecommunications, tuners instrumental and hybrid ICs.

DIMENSIONS

Unit : mm
(Dimensions in inches)

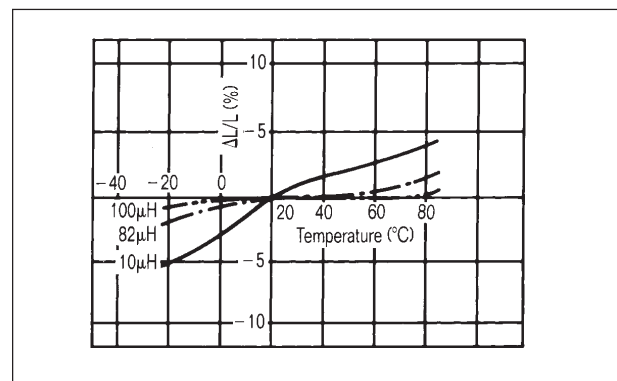
Type	L	W	T	D	E	F
WICF1008	2.5 \pm 0.2 (.100 \pm .008)	2.0 \pm 0.2 (.080 \pm .008)	1.8 \pm 0.2 (.072 \pm .008)	1.4 \pm 0.1 (.056 \pm .004)	0.5 \pm 0.005 (.02 \pm .002)	0.4 \pm 0.005 (.016 \pm .002)
WICF1210	3.2 \pm 0.2 (.126 \pm .008)	2.5 \pm 0.2 (.098 \pm .008)	2.2 \pm 0.2 (.087 \pm .008)	1.9 \pm 0.1 (.075 \pm .004)	0.5 \pm 0.005 (.02 \pm .002)	0.4 \pm 0.005 (.016 \pm .002)
WICF1812	4.5 \pm 0.3 (.177 \pm .008)	3.2 \pm 0.2 (.126 \pm .008)	3.2 \pm 0.2 (.126 \pm .008)	2.6 \pm 0.1 (.102 \pm .004)	0.5 \pm 0.005 (.02 \pm .002)	0.4 \pm 0.005 (.016 \pm .002)



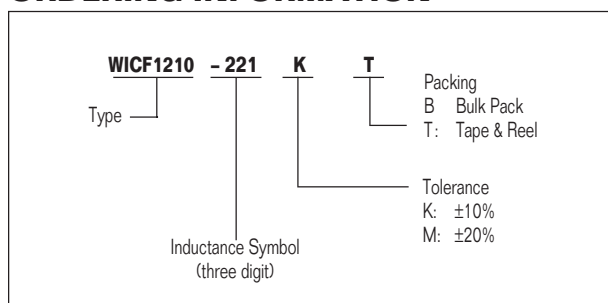
CHARACTERISTICS

Temperature rise	20°C max.
Ambient temperature	80°C
Storage temperature	-40°C to + 100°C
Operating temperature	-20°C to + 100°C
Terminal tensile strength	1 kg min. (0.5kg for the WICF1210 & WICF1008)
Current rating	Value obtained when current flows and when temperature has risen to 20°C or value obtained when LC current flows and when the initial value of inductance has fallen by 10%, whichever smaller.
Resistance to soldering heat	260°C 10 seconds
Resistance to solvent	Conforms to MIL-STD-202E

TEMPERATURE CHARACTERISTICS



ORDERING INFORMATION



TAPE PACKAGING

Size	Qty/Reel
WICF1008	2,000
WICF1210	2,000
WICF1812	500

WOUND SHIELDED INDUCTOR CHIPS — TYPE WICF

WICF1008 ELECTRICAL SPECIFICATIONS

SMEC Part No.	Inductance (μH)	Inductance Symbol	Q min.	L,Q test frequency (MHz)	Self resonant frequency (MHz) min.	DC resistance (Ω) max.	I _{dc} (mA) max.
WICF1008-1R0MT	1.0	1R0	10	7.96	100	0.13	455
WICF1008-1R5MT	1.5	1R5	10	7.96	80	0.17	350
WICF1008-2R2MT	2.2	2R2	10	7.96	70	0.20	315
WICF1008-3R3MT	3.3	3R3	10	7.96	55	0.25	280
WICF1008-4R7MT	4.7	4R7	10	7.96	45	0.30	210
WICF1008-6R8MT	6.8	6R8	10	7.96	38	0.35	175
WICF1008-100KT	10	100	20	2.52	32	0.50	155
WICF1008-150KT	15	150	20	2.52	28	0.75	130
WICF1008-220KT	22	220	20	2.52	16	1.60	105
WICF1008-330KT	33	330	20	2.52	14	2.10	85
WICF1008-470KT	47	470	20	2.52	11	2.60	60
WICF1008-680KT	68	680	20	2.52	10	3.30	50
WICF1008-101KT	100	101	20	0.796	8	5.50	40

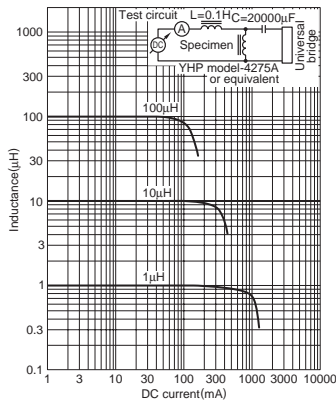
Inductance and Q are measured with a Q-meter.

WICF1210 ELECTRICAL SPECIFICATIONS

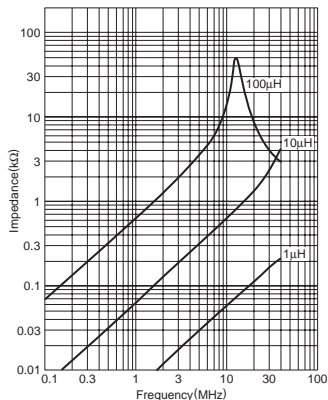
SMEC Part No.	Inductance (μH)	Inductance Symbol	Q min.	L,Q test frequency (MHz)	Self resonant frequency (MHz) min.	DC resistance (Ω) max.	I _{dc} (mA) max.
WICF1210-1R0MT	1.0	1R0	5	7.96	100	0.06	1250
WICF1210-1R5MT	1.5	1R5	5	7.96	80	0.08	1100
WICF1210-2R2MT	2.2	2R2	5	7.96	68	0.09	1000
WICF1210-3R3MT	3.3	3R3	5	7.96	54	0.11	900
WICF1210-4R7MT	4.7	4R7	5	7.96	46	0.13	850
WICF1210-6R8MT	6.8	6R8	5	7.96	38	0.17	750
WICF1210-100KT	10	100	10	2.52	30	0.26	650
WICF1210-150KT	15	150	10	2.52	26	0.32	550
WICF1210-220KT	22	220	10	2.52	21	0.50	450
WICF1210-330KT	33	330	10	2.52	17	0.75	360
WICF1210-470KT	47	470	10	2.52	14	0.95	320
WICF1210-680KT	68	680	10	2.52	12	1.50	260
WICF1210-101KT	100	101	10	0.796	10	2.50	200
WICF1210-151KT	150	151	10	0.796	8	3.20	170
WICF1210-221KT	220	221	10	0.796	7	5.40	130
WICF1210-331KT	330	331	10	0.796	5	7.00	110
WICF1210-471KT	470	471	10	0.796	4	16.0	79
WICF1210-681KT	680	681	10	0.796	3	20.0	70
WICF1210-102KT	1000	102	10	0.252	2.4	24.0	63

Inductance and Q are measured with a Q-meter.

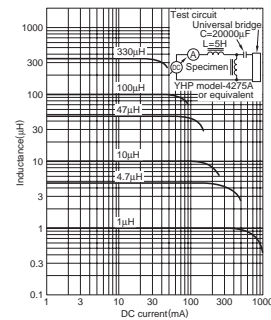
ELECTRICAL CHARACTERISTICS Inductance vs. Frequency Characteristics



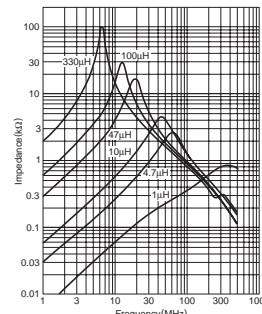
Impedance vs. Frequency Characteristics



ELECTRICAL CHARACTERISTICS Inductance vs. Frequency Characteristics



Impedance vs. Frequency Characteristics



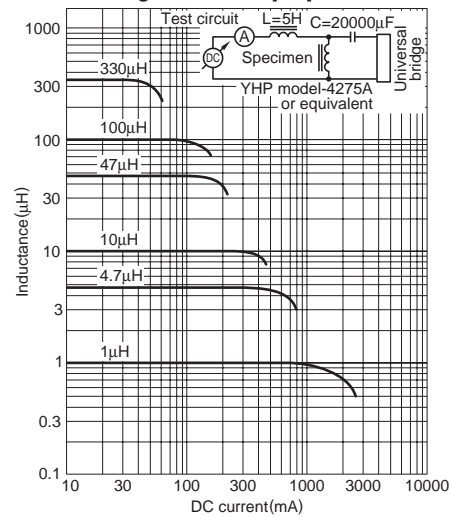
WOUND SHIELDED INDUCTOR CHIPS — TYPE WICF

WICF1812 ELECTRICAL SPECIFICATIONS

SMEC Part No.	Inductance (μH)	Inductance Symbol	Q min.	L, Q test frequency (MHz)	Self resonant frequency (MHz) min.	DC resistance (Ω) max.	I _{dc} (mA) max.
WICF1812-1R0MT	1.0	1R0	10	7.96	200	0.05	1400
WICF1812-1R5MT	1.5	1R5	10	7.96	130	0.06	1200
WICF1812-2R2MT	2.2	2R2	10	7.96	80	0.07	1100
WICF1812-3R3MT	3.3	3R3	10	7.96	45	0.09	1050
WICF1812-4R7MT	4.7	4R7	10	7.96	35	0.10	1000
WICF1812-6R8MT	6.8	6R8	10	7.96	28	0.14	840
WICF1812-100KT	10.0	100	10	2.52	22	0.21	690
WICF1812-150KT	15.0	150	10	2.52	20	0.30	570
WICF1812-220KT	22.0	220	10	2.52	18	0.46	460
WICF1812-330KT	33.0	330	10	2.52	14	0.63	400
WICF1812-470KT	47.0	470	10	2.52	11.5	0.85	340
WICF1812-680KT	68.0	680	10	2.52	10.0	1.20	280
WICF1812-101KT	100	101	10	0.796	8.0	1.70	240
WICF1812-151KT	150	151	10	0.796	7.0	2.30	200
WICF1812-221KT	220	221	10	0.796	5.5	3.8	160
WICF1812-331KT	330	331	10	0.796	4.0	6.0	120

Inductance and Q are measured with a Q-meter.

ELECTRICAL CHARACTERISTICS Inductance Change vs. DC Superposition Characteristics



Impedance vs. Frequency Characteristics

